JC12 Rec'd PCT/FTC 1 9 OCT 2005

SHEET 1 OF 1

| INFO | | | ON DISCLOS | SURE | ATTY. DOCKET NO. 071971-0388 | SERIAL NO. | | | | | |
|------------------------|---------------|---|---|--------------------------------|---|--|-----------------------------------|----------------------------------|---|--|--|
| CITATION IN AN | | | | | 01 131 1-0300 | | Not yet assigned | | | | |
| APPLICATION | | | | | 1 | | 10/5 | 10/553628 | | | |
| | | | | | APPLICANT Masao UCHIDA | , et al. | | | | | |
| (PTO-1449) | | | | | | | ROUP 2814 lot yot assigned | | | | |
| | | | U | .S. PATENT | DOCUMENTS | • | | | | | |
| EXAMINER'S INITIALS | CITE NO. | | Document Number nber-Kind Code2 (1/ known) | Publication Date MM-DD-YYYY | Name of Patentee or Appli Document | Name of Patentee or Applicant of Cited Document | | | Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear | | |
| Mbh | | US 2003/0080384 A1 | | | | | Corresp | Corresponds to JP 2003-234301 | | | |
| Mbh | | US 5977564 A | | | | | Corres | Corresponds to JP 10-321854 | | | |
| Mbh | | υs | 6097039 A | | | | . Corresp | onds to JP 2001 | -517375 / | | |
| | | US | | | | | | | | | |
| | | US | | | | | | | | | |
| | | US | | | | | | | | | |
| | | US | | | | | | | | | |
| | L | 1001 | | FOREIGN PAT | ENT DOCUMENTS | | | | | | |
| EXAMINER'S | | Foreign Patent Document | | Publication Date | Name of Patentee or | Pages, Co | Pages, Columns, Lines Translation | | ion | | |
| initials | -CITE- NO. | Country Codes=Number a=Kind Codes (if known) | | MM-DD-YYYY | -Applicant of Cited Document - | | | | Yes No | | |
| Mbh | | JP 2003-234301 A | | 08-22-2003 | Matsushita Electric Industrial Co., Ltd. | Corresponds to US 2003/0080384 A1 | | | | | |
| Mbh | | | JP 2003-209251 A | 07-25-03 | Japan Atomic Energy Research Institute | | | | | | |
| Mbh | | JP 10-321854 A | | 12-04-1998 | Toshiba Corp. | Corresponds to US 5977564 A | | • | | | |
| Mbh | <u> </u> | | JP 2000-294777 A | 10-20-2000 | Mitsubishi Electric Corp. | | | | | | |
| Mbh | | | JP 2001-517375 A | 10-02-2001 | Siemens AG. | Corresponds to US 6097039 A | | | | | |
| Mbh | | | JP 2001-144288 A | 05-25-2001 | Denso Corp. | | | | | | |
| Mbh | | | JP 2002-280381 A | 09-27-2002 | Fujl Electric Co., Ltd. | | | | ļ | | |
| Mbh | | | WO 99/48153 | 09-23-1999 | HITACHI, LTD. | | | JAPAN (w/English Abstract) | | | |
| • | | | | | r, Title, Date, Pertinent Pages, E | | | | | | |
| EXAMINER'S INITIALS | CITE NO. | Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published. | | | | | | | | | |
| Mbh | | G.Y. CHUNG, et al., "Improved Invention Channel Mobility for 4H-SIC MOSFETs Following High Temperature Anneals in Nitric Oxide," Electron Device Letters, April 2001, pp 176-178, Vol 22, No. 4, IEEE | | | | | | | | | |
| | | | | | | | | | | | |
| | | | | | | | | | | | |
| | | | AMINER | | 00.4 | DATE CON: | SIDERED | | | | |
| | csalir | | | | U 2 / e with MPEP 609. Draw line thro | | | | | | |

^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Applicant's unique citation designation number (optional). 2 Applicant is to place a check mark here if English language Translation is attached.